

11 February 2021

Product data sheet

1. General description

Dual, Logic level N-channel MOSFET in an LFPAK56D package, using Trench 9 TrenchMOS technology. This product has been designed and qualified to AEC-Q101 for use in high performance automotive applications

2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
- Trench 9 superjunction technology:
- · Low power losses, high power density
- LFPAK copper clip package technology:
 - High robustness and reliability
 - Gull wing leads for high manufacturability and AOI
- Repetitive avalanche rated

3. Applications

- 12 V, 24 V and 48 V automotive systems
- Motors, lamps and solenoid control
- Transmission control
- DC-to-DC conversion

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	42	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	46	W
Static chara	acteristics FET1 and FET2						
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 10 A; T _j = 25 °C; Fig. 11		9.8	14.1	16.9	mΩ
Dynamic ch	naracteristics FET1 and FE	T2					
Q _{GD}	gate-drain charge	$ I_D = 10 \text{ A}; \text{ V}_{DS} = 32 \text{ V}; \text{ V}_{GS} = 5 \text{ V}; \\ T_j = 25 \text{ °C}; \frac{\text{Fig. 13}}{\text{Fig. 14}}; \frac{\text{Fig. 14}}{\text{Fig. 14}} $		-	1.8	4.2	nC
Source-drai	in diode FET1 and FET2						
Q _r	recovered charge		[2]	-	16.2	-	nC

42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, [1] thermal design and operating temperature.

Includes capacitive recovery [2]

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	8 7 6 5	D1 D1 D2 D2
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		S1 G1 S2 G2
7	D1	drain1		mbk725
8	D1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BUK9K13-40H	LFPAK56D; Dual LFPAK	plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK9K13-40H	91340нк

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{GS}	gate-source voltage	DC; T _j = 25 °C		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	46	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	42	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	30	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	169	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain	n diode FET1 and FET2		·			
ls	source current	T _{mb} = 25 °C		-	42	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	169	А

BUK9K13-40H

Dual N-channel 40 V, 13 mOhm logic level MOSFET in LFPAK56D

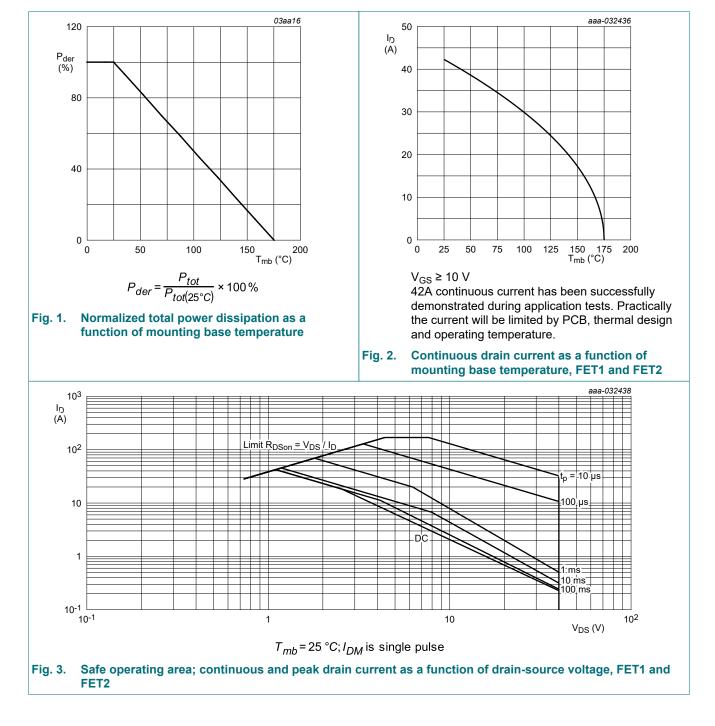
Symbol	Parameter	Conditions		Min	Max	Unit
Avalanche Ruggedness FET1 and FET2						
E _{DS(AL)S}		$ I_D = 39.9 \text{ A}; V_{sup} \le 40 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \\ V_{\text{GS}} = 10 \text{ V}; \text{T}_{\text{j(init)}} = 25 ^{\circ}\text{C}; \text{Fig. 4} $	[2] [3]	-	10.6	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 40 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R _{GS} = 50 Ω; Fig. 4	[4]	-	39.9	A

[1] 42A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

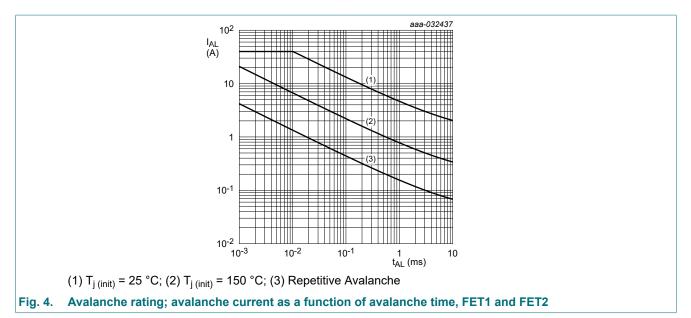
[3] Refer to application note AN10273 for further information.

[4] Protected by 100% test



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Dual N-channel 40 V, 13 mOhm logic level MOSFET in LFPAK56D



9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
₹th(j-mb)	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	3	3.23	K/W
10 Z _{th(i-mb)} (K/W) δ = 0.5 0.2 0.1					naa-032439	



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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
-	acteristics FET1 and FET2					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _i = 25 °C	40	43	_	V
· (BR)D33	breakdown voltage	$I_D = 250 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_i = -40 \ ^{\circ}\text{C}$	-	40.5	_	V
		$I_D = 250 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_i = -55 \ ^{\circ}\text{C}$	36	40	_	V
V _{GS(th)}	gate-source threshold	$I_D = 1 \text{ mA; } V_{DS} = V_{GS}; T_i = 25 \text{ °C; Fig. 9;}$	1.5	1.85	2.2	V
• GS(III)	voltage	Fig. 10	1.0	1.00		•
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C;	0.7	-	-	V
		Fig. 10				
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 10</u>	-	-	2.6	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C	-	0.01	5	μA
		V _{DS} = 16 V; V _{GS} = 0 V; T _j = 125 °C	-	0.14	10	μA
		V_{DS} = 40 V; V_{GS} = 0 V; T_j = 175 °C	-	26	500	μA
I _{GSS}	gate leakage current	V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; <u>Fig. 11</u>	7.9	11.4	13.6	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 105 °C; <u>Fig. 12</u>	10.9	16	20.4	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 125 °C; Fig. 12	12	17.4	21.9	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C; Fig. 12	14.5	20.9	26.4	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 25 °C; Fig. 11	9.8	14.1	16.9	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 105 °C; Fig. 12	13.5	20	25.4	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 125 °C; Fig. 12	14.8	21.6	27.2	mΩ
		V _{GS} = 4.5 V; I _D = 10 A; T _j = 175 °C; Fig. 12	18	26.6	32.8	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.7	1.8	4.2	Ω
Dynamic ch	naracteristics FET1 and FE	T2				
Q _{G(tot)}	total gate charge	$ I_D = 10 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V}; $	-	13	19.4	nC
		I _D = 10 A; V _{DS} = 32 V; V _{GS} = 5 V;	-	6.8	10.2	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	-	2.3	3.8	nC
Q _{GD}	gate-drain charge	1 -	-	1.8	4.2	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;	-	848	1160	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	-	280	420	pF
C _{rss}	reverse transfer capacitance		-	39	84	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 32 V; R_L = 3.2 \Omega; V_{GS} = 5 V;$	-	6.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	9.7	-	ns
t _{d(off)}	turn-off delay time		_	10.1	-	ns

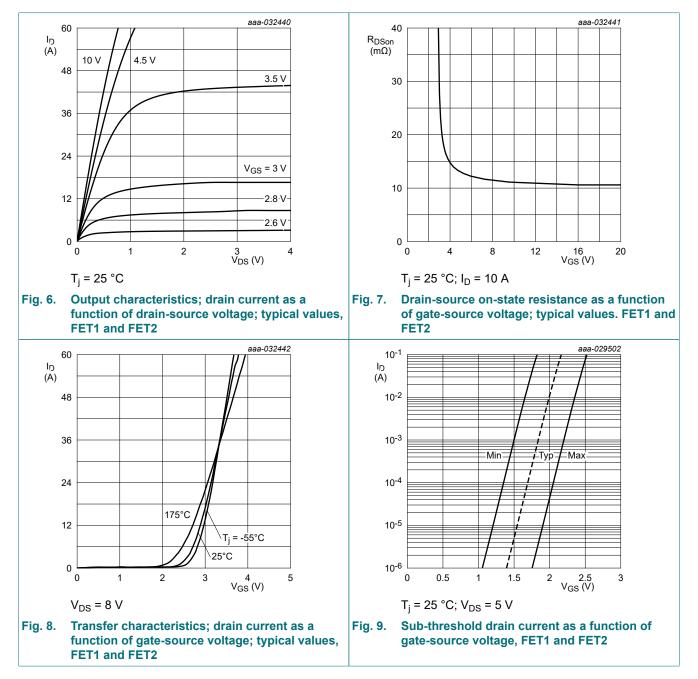
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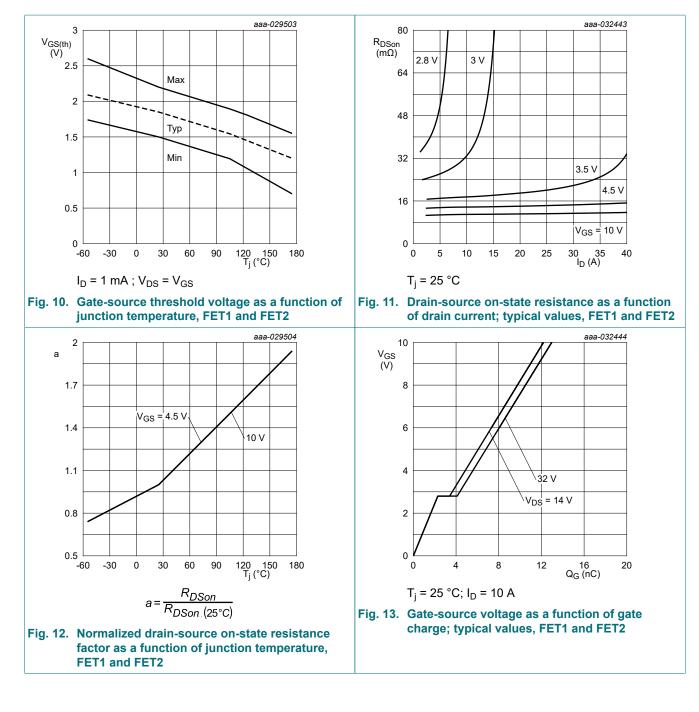
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Dual N-channel 40 V, 13 mOhm logic level MOSFET in LFPAK56D

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
t _f	fall time			-	7.8	-	ns	
Source-drain diode FET1 and FET2								
V _{SD}	source-drain voltage	I _S = 10 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 16</u>		-	0.81	1	V	
t _{rr}		I_{S} = 10 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;		-	21.5	-	ns	
Q _r	recovered charge	V _{DS} = 20 V; T _j = 25 °C	[1]	-	16.2	-	nC	

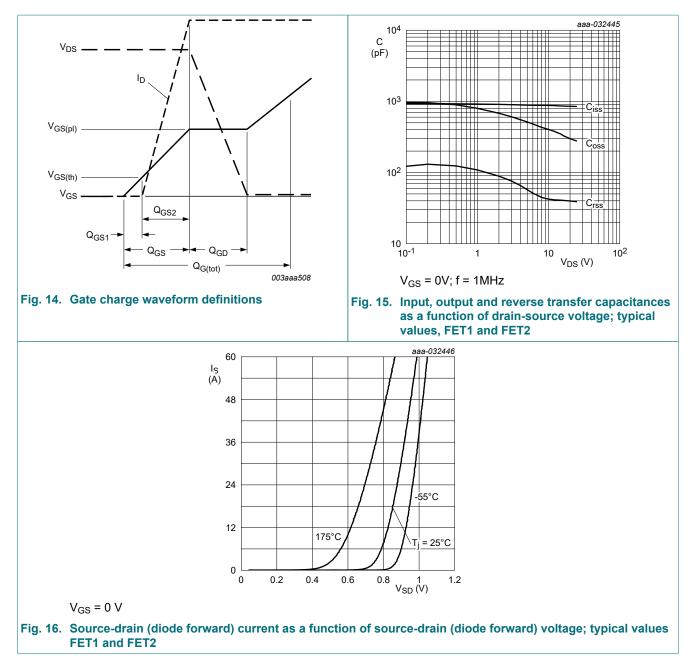
[1] Includes capacitive recovery



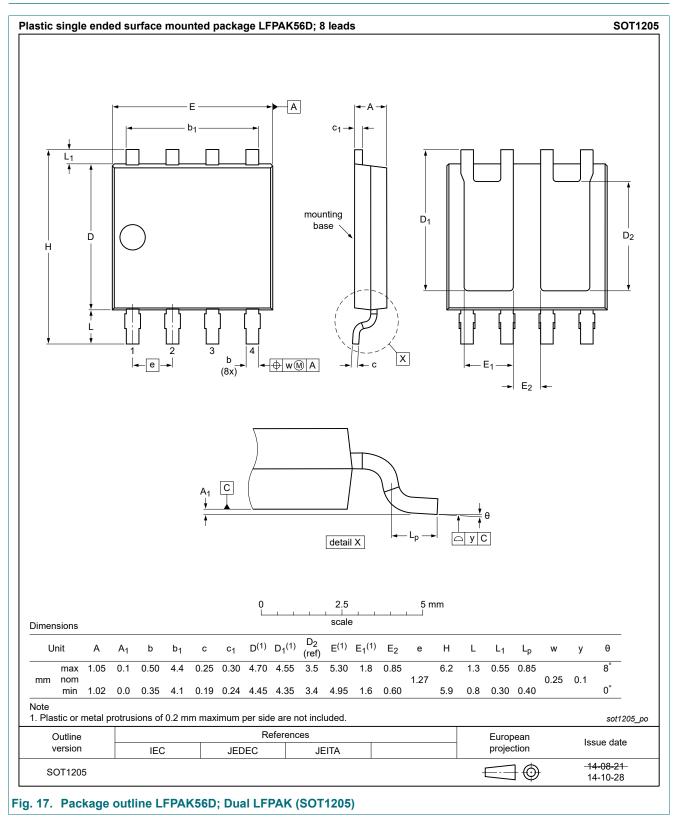


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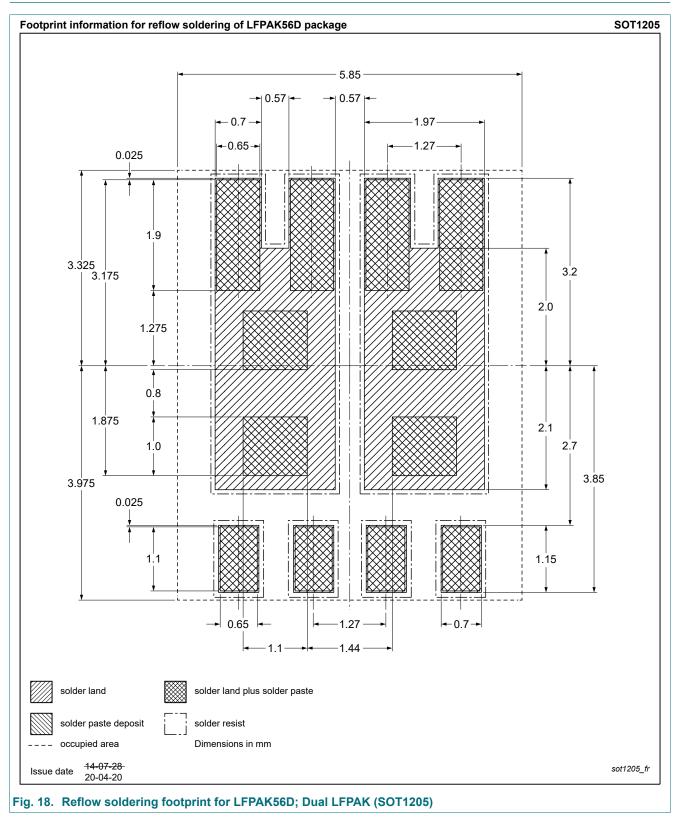
Dual N-channel 40 V, 13 mOhm logic level MOSFET in LFPAK56D



11. Package outline



12. Soldering



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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